TEXAS INSTRUMENTS

TCAN1044AEV-Q1
SLLSFN9 – OCTOBER 2021

TCAN1044AEV-Q1 Grade 0 Fault-Protected CAN FD Transceiver with 1.8-V I/O Support

1 Features

- AEC-Q100 (Grade 0) Qualified for automotive applications
- Meets the requirements of ISO 11898-2:2016 physical layer standard
- Functional Safety-Capable
  - Documentation available to aid in functional safety system design
- Support of classical CAN and optimized CAN FD performance at 2, 5, and 8 Mbps
  - Short and symmetrical propagation delays for enhanced timing margin
- I/O voltage range supports 1.7 V to 5.5 V
- Support for 12-V and 24-V battery applications
- Receiver common mode input voltage: ±12 V
- Protection features:
  - Bus fault protection: ±58 V
  - Undervoltage protection
  - TXD-dominant time-out (DTO)
    - Data rates down to 9.2 kbps
  - Thermal-shutdown protection (TSD)
- Operating modes:
  - Normal mode
  - Low power standby mode supporting remote wake-up request
- Optimized behavior when unpowered
  - Bus and logic pins are high impedance (no load to operating bus or application)
  - Hot-plug capable: power up/down glitch-free operation on bus and RXD output
- 8-Pin SOIC and small footprint SOT-23 package

2 Applications

- Automotive and transportation
  - Body control modules
  - Automotive gateway
  - Advanced driver assistance system (ADAS)
  - Infotainment

3 Description

The TCAN1044AEV-Q1 is a high-speed controller area network (CAN) transceiver that meets the physical layer requirements of the ISO 11898-2:2016 high-speed CAN specification.
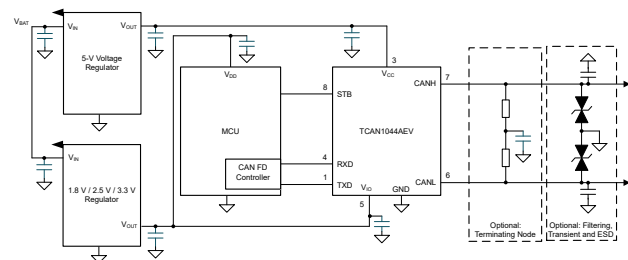
The transceiver has a certified electromagnetic compatibility (EMC) operation making it a suitable choice for classical CAN and CAN FD networks up to 5 megabits per second (Mbps). Up to 8 Mbps operation in simpler networks is possible with these devices. The device includes internal logic level translation via the V_{IO} pin to allow for interfacing the transceiver I/O's directly to 1.8-V, 2.5-V, 3.3-V, or 5-V logic levels. The transceiver supports a low-power standby mode and wake over CAN which is compliant to the ISO 11898-2:2016 defined wake-up pattern (WUP).

The transceiver also includes thermal-shutdown (TSD), TXD-dominant time-out (DTO), supply undervoltage detection, and ±58-V bus fault protection. The device has defined fail-safe behavior in supply undervoltage or floating pin scenarios.

Device Information

PART NUMBER	PACKAGE[1]	BODY SIZE (NOM)
TCAN1044AEV-Q1	SOIC (D)	4.90 mm x 3.91 mm
	SOT-23 (DDF)	2.90 mm x 1.60 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.
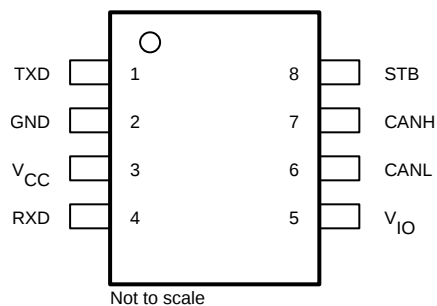

Simplified Schematic

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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

DATE	REVISION	NOTES
October 2021	*	Initial Release

5 Pin Configuration and Functions

Figure 5-1. DDF (SOT) and D (SOIC), 8-Pin Package, Top View

Table 5-1. Pin Functions

Pins		Type	Description
No.	Name		
1	TXD	Digital Input	CAN transmit data input; integrated pull-up
2	GND	GND	Ground connection
3	V_{CC}	Supply	5-V supply voltage
4	RXD	Digital Output	CAN receive data output, tri-stated when device powered off
5	V_{IO}	Supply	I/O supply voltage
6	CANL	Bus IO	Low-level CAN bus input/output line
7	CANH	Bus IO	High-level CAN bus input/output line
8	STB	Digital Input	Standby input for mode control; integrated pull-up

Product Folder Links: *TCAN1044AEV-Q1*

6 Specifications

6.1 Absolute Maximum Ratings

(1) (2)

		MIN	MAX	UNIT
V_{CC}	Supply voltage	−0.3	6	V
V_{IO}	Supply voltage I/O level shifter	−0.3	6	V
V_{BUS}	CAN Bus I/O voltage	−58	58	V
V_{DIFF}	Max differential voltage between CANH and CANL	−45	45	V
V_{Logic_Input}	Logic input terminal voltage	−0.3	6	V
V_{RXD}	RXD output terminal voltage range	−0.3	6	V
$I_{O(RXD)}$	RXD output current	−8	8	mA
T_J	Junction temperature	−40	175	°C
T_{STG}	Storage temperature	−65	150	°C

(1)   Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
(2)   All voltage values, except differential I/O bus voltages, are with respect to ground terminal.

6.2 ESD Ratings

				VALUE	UNIT
V_{ESD}	Electrostatic discharge	Human-body model (HBM), per AEC Q100-002[1]	HBM classification level 3A for all pins	±4000	V
			HBM classification level 3B for global pins CANH and CANL with respect to GND	±10000	V
		Charged-device model (CDM), per AEC Q100-011 CDM classification level C5 for all pins		±750	V

(1)   AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 ESD Ratings - IEC Specifications

				VALUE	UNIT
V_{ESD}	System level Electrostatic discharge	CAN bus terminals to GND	Unpowered contact discharge per ISO 10605 [1]	±8000	V
			SAE J2962-2 per ISO 10605 Powered Contact Discharge [2]	±8000	V
			SAE J2962-2 per ISO 10605 Powered Air Discharge [2]	±15000	V
V_{Tran}	Transient voltage per ISO 7637-2[3]		Pulse 1	−100	V
			Pulse 2a	75	V
			Pulse 3a	−150	V
			Pulse 3b	100	V
	Transient voltage per ISO 7637-3[4]		DCC slow transient pulse	±30	V

(1)   Tested according to IEC 62228-3:2019 CAN Transceivers.
(2)   Results given here are specific to the SAE J2962-2 Communication Transceivers Qualification Requirements - CAN. Testing performed by OEM approved independent third party, EMC report available upon request.
(3)   Tested according to IEC 62228-3:2019 CAN Transceivers.
(4)   Tested according to SAE J2962-2.

6.4 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage	4.5	5	5.5	V
V_{IO}	Supply voltage for I/O level shifter	1.7		5.5	V
$I_{OH(RXD)}$	RXD terminal high-level output current	−1.5			mA
$I_{OL(RXD)}$	RXD terminal low-level output current			1.5	mA
T_A	Operating ambient temperature	-40		150	℃

6.5 Thermal Characteristics

THERMAL METRIC[1]		TCAN1044AEV-Q1		UNIT
		D (SOIC)	DDF (SOT)	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	127.5	122	℃/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	67.6	63	℃/W
$R_{\theta JB}$	Junction-to-board thermal resistance	70.9	42.4	℃/W
Ψ_{JT}	Junction-to-top characterization parameter	19.3	2.4	℃/W
Ψ_{JB}	Junction-to-board characterization parameter	70.2	42.2	℃/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	--	--	℃/W

(1)   For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.6 Supply Characteristics

Over recommended operating conditions with T_A = -40℃ to 150℃ (unless otherwise noted)

PARAMETER			TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{CC}	Supply current Normal mode	Dominant	STB = 0 V, TXD = 0 V R_L = 60 Ω, C_L = open See Figure 7-1		45	70	mA
			STB = 0 V, TXD = 0 V R_L = 50 Ω, C_L = open See Figure 7-1		49	80	mA
		Recessive	STB = 0 V, TXD = V_{CC} or V_{IO} R_L = 50 Ω, C_L = open See Figure 7-1		4.5	7.5	mA
		Dominant with bus fault	STB = 0 V, TXD = 0 V CANH = CANL = ±25 V R_L = open, C_L = open See Figure 7-1			130	mA
	Supply current Standby mode		STB = TXD = V_{IO} R_L = 50 Ω, C_L = open See Figure 7-1			1.5	µA
I_{IO}	I/O supply current Normal mode	Dominant	STB = 0 V, TXD = 0 V RXD floating		125	300	µA
	I/O supply current Normal mode	Recessive	STB = 0 V, TXD = 0 V RXD floating		25	48	µA
	I/O supply current Standby mode		STB = V_{IO}, TXD = 0 V RXD floating		8.5	14	µA
UV_{CC}	Rising undervoltage detection on V_{CC} for protected mode				4.2	4.4	V
	Falling undervoltage detection on V_{CC} for protected mode			3.5	4	4.25	V
$V_{HYS(UVCC)}$	Hysteresis voltage on UV_{CC}				200		mV
UV_{VIO}	Rising undervoltage detection on V_{IO}				1.56	1.65	V
	Falling undervoltage detection on V_{IO}			1.4	1.51	1.59	V
$V_{HYS(UVIO)}$	Hysteresis voltage on UV_{VIO}				40		mV

Product Folder Links: TCAN1044AEV-Q1

6.7 Dissipation Ratings

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
P_D	Average power dissipation Normal mode	V_{CC} = 5 V, V_{IO} = 1.8 V, T_J = 27°C, R_L = 60 Ω, C_{L_RXD} = 15 pF TXD input = 250 kHz 50% duty cycle square wave		95		mW
		V_{CC} = 5 V, V_{IO} = 3.3 V, T_J = 27°C, R_L = 60 Ω, C_{L_RXD} = 15 pF TXD input = 250 kHz 50% duty cycle square wave		95		mW
		V_{CC} = 5 V, V_{IO} = 5 V, T_J = 27°C, R_L = 60 Ω, C_{L_RXD} = 15 pF TXD input = 250 kHz 50% duty cycle square wave		95		mW
		V_{CC} = 5.5 V, V_{IO} = 1.8 V, T_J = 150°C, R_L = 60Ω, C_{L_RXD} = 15 pF TXD input = 2.5 MHz 50% duty cycle square wave		120		mW
		V_{CC} = 5.5 V, V_{IO} = 3.3 V, T_J = 150°C, R_L = 60 Ω, C_{L_RXD} = 15 pF TXD input = 2.5 MHz 50% duty cycle square wave		120		mW
		V_{CC} = 5.5 V, V_{IO} = 5 V, T_J = 150°C, R_L = 60 Ω, C_{L_RXD} = 15 pF TXD input = 2.5 MHz 50% duty cycle square wave		120		mW
T_{TSD}	Thermal shutdown temperature		175	195	210	°C
$T_{TSD(HYS)}$	Thermal shutdown hysteresis			12		

6.8 Electrical Characteristics

Over recommended operating conditions with T_A = -40°C to 150°C (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Driver Electrical Characteristics							
$V_{O(DOM)}$	Dominant output voltage Normal mode	CANH	STB = 0 V, TXD = 0 V 50 Ω ≤ R_L ≤ 65 Ω, C_L = open, R_{CM} = open See Figure 7-2 and Figure 8-3	2.75		4.5	V
		CANL		0.5		2.25	V
$V_{O(REC)}$	Recessive output voltage Normal mode	CANH and CANL	STB = 0 V, TXD = V_{IO} R_L = open (no load), R_{CM} = open See Figure 7-2 and Figure 8-3	2	0.5 V_{CC}	3	V
V_{SYM}	Driver symmetry $(V_{O(CANH)} + V_{O(CANL)})/V_{CC}$		STB = 0 V, TXD = 250 kHz, 1 MHz, 2.5 MHz R_L = 60 Ω, C_{SPLIT} = 4.7 nF, C_L = open, R_{CM} = open See Figure 7-2 and Figure 9-2	0.9		1.1	V/V
V_{SYM_DC}	DC output symmetry $(V_{CC} - V_{O(CANH)} - V_{O(CANL)})$		STB = 0 V R_L = 60 Ω, C_L = open See Figure 7-2 and Figure 8-3	−400		400	mV
$V_{OD(DOM)}$	Differential output voltage Normal mode Dominant	CANH - CANL	STB = 0 V, TXD = 0 V 50 Ω ≤ R_L ≤ 65 Ω, C_L = open See Figure 7-2 and Figure 8-3	1.5		3	V
			STB = 0 V, TXD = 0 V 45 Ω ≤ R_L ≤ 70 Ω, C_L = open See Figure 7-2 and Figure 8-3	1.4		3.3	V
			STB = 0 V, TXD = 0 V R_L = 2240 Ω, C_L = open See Figure 7-2 and Figure 8-3	1.5		5	V
$V_{OD(REC)}$	Differential output voltage Normal mode Recessive	CANH - CANL	STB = 0 V, TXD = V_{IO} R_L = 60 Ω, C_L = open See Figure 7-2 and Figure 8-3	−120		12	mV
			STB = 0 V, TXD = V_{IO} R_L = open, C_L = open See Figure 7-2 and Figure 8-3	−50		50	mV

6.8 Electrical Characteristics (continued)

Over recommended operating conditions with T_A = -40℃ to 150℃ (unless otherwise noted)

PARAMETER			TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{O(STB)}$	Bus output voltage Standby mode	CANH	STB = V_{IO} R_L = open See Figure 7-2 and Figure 8-3	-0.1		0.1	V
		CANL		-0.1		0.1	V
		CANH - CANL		-0.2		0.2	V
$I_{OS(SS\_DOM)}$	Short-circuit steady-state output current, dominant Normal mode		STB = 0 V, TXD = 0 V $V_{(CANH)}$ = -15 V to 40 V, CANL = open See Figure 7-7 and Figure 8-3	−115			mA
			STB = 0 V, TXD = 0 V $V_{(CAN\_L)}$ = -15 V to 40 V, CANH = open See Figure 7-7 and Figure 8-3			115	mA
$I_{OS(SS\_REC)}$	Short-circuit steady-state output current, recessive Normal mode		STB = 0 V, TXD = V_{IO} −27 V ≤ V_{BUS} ≤ 32 V, where V_{BUS} = CANH = CANL See Figure 7-7 and Figure 8-3	−5		5	mA
Receiver Electrical Characteristics							
V_{IT}	Input threshold voltage Normal mode		STB = 0 V -12 V ≤ V_{CM} ≤ 12 V See Figure 7-3 and Table 8-5	500		900	mV
$V_{IT(STB)}$	Input threshold Standby mode		STB = V_{IO} -12 V ≤ V_{CM} ≤ 12 V See Figure 7-3 and Table 8-5	400		1150	mV
V_{DOM}	Dominant state differential input voltage range Normal mode		STB = 0 V -12 V ≤ V_{CM} ≤ 12 V See Figure 7-3 and Table 8-5	0.9		9	V
V_{REC}	Recessive state differential input voltage range Normal mode		STB = 0 V -12 V ≤ V_{CM} ≤ 12 V See Figure 7-3 and Table 8-5	-4		0.5	V
$V_{DOM(STB)}$	Dominant state differential input voltage range Standby mode		STB = V_{IO} -12 V ≤ V_{CM} ≤ 12 V See Figure 7-3 and Table 8-5	1.15		9	V
$V_{REC(STB)}$	Recessive state differential input voltage range Standby mode		STB = V_{IO} -12 V ≤ V_{CM} ≤ 12 V See Figure 7-3 and Table 8-5	-4		0.4	V
V_{HYS}	Hysteresis voltage for input threshold Normal mode		STB = 0 V -12 V ≤ V_{CM} ≤ 12 V See Figure 7-3 and Table 8-5		115		mV
V_{CM}	Common-mode range Normal and standby modes		See Figure 7-3 and Table 8-5	−12		12	V
$I_{LKG(IOFF)}$	Unpowered bus input leakage current		CANH = CANL = 5 V, V_{CC} = V_{IO} = GND			5	µA
C_I	Input capacitance to ground (CANH or CANL)		TXD = V_{IO}			20	pF
C_{ID}	Differential input capacitance					10	pF
R_{ID}	Differential input resistance		STB = 0 V, TXD = V_{IO} -12 V ≤ V_{CM} ≤ 12 V	40		90	kΩ
R_{IN}	Single-ended input resistance (CANH or CANL)			20		45	kΩ
$R_{IN(M)}$	Input resistance matching $[1 − (R_{IN(CANH)} / R_{IN(CANL)})] × 100$ %		$V_{(CAN\_H)}$ = $V_{(CAN\_L)}$ = 5 V	−1		1	%
TXD Terminal (CAN Transmit Data Input)							
V_{IH}	High-level input voltage			0.7 V_{IO}			V
V_{IL}	Low-level input voltage					0.3 V_{IO}	V
I_{IH}	High-level input leakage current		TXD = V_{CC} = V_{IO} = 5.5 V	−2.5	0	1	µA
I_{IL}	Low-level input leakage current		TXD = 0 V V_{CC}= V_{IO} = 5.5 V	−200	-100	−20	µA
$I_{LKG(OFF)}$	Unpowered leakage current		TXD = 5.5 V V_{CC}= V_{IO} = 0 V	−1	0	1	µA
C_I	Input capacitance		V_{IN} = 0.4×sin($2×π×2×10^6×t$)+2.5 V		5		pF
RXD Terminal (CAN Receive Data Output)							
V_{OH}	High-level output voltage		I_O = −1.5 mA See Figure 7-3	0.8 V_{IO}			V

Product Folder Links: TCAN1044AEV-Q1

6.8 Electrical Characteristics (continued)

Over recommended operating conditions with T_A = -40℃ to 150℃ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{OL}	Low-level output voltage	I_O = 1.5mA See Figure 7-3			0.2 V_{IO}	V
$I_{LKG(OFF)}$	Unpowered leakage current	RXD = 5.5 V V_{CC} = V_{IO} = 0 V	−1	0	1	µA
STB Terminal (Standby Mode Input)						
V_{IH}	High-level input voltage		0.7 V_{IO}			V
V_{IL}	Low-level input voltage				0.3 V_{IO}	V
I_{IH}	High-level input leakage current	V_{CC} = V_{IO} = STB = 5.5 V	−2		2	µA
I_{IL}	Low-level input leakage current	STB = 0 V V_{CC} = V_{IO} = 5.5 V,	−20		−2	µA
$I_{LKG(OFF)}$	Unpowered leakage current	STB = 5.5V V_{CC} = V_{IO} = 0 V	−1	0	1	µA

6.9 Switching Characteristics

Over recommended operating conditions with T_A = -40℃ to 150℃ (unless otherwise noted).

| PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Device Switching Characteristics						
$t_{PROP(LOOP1)}$	Total loop delay Driver input (TXD) to receiver output (RXD), recessive to dominant	STB = 0 V, V_{IO} = 2.8 V to 5.5 V R_L = 60 Ω, C_L = 100 pF, $C_{L(RXD)}$ = 15 pF See Figure 7-4		125	210	ns
$t_{PROP(LOOP1)}$	Total loop delay Driver input (TXD) to receiver output (RXD), recessive to dominant	STB = 0 V, V_{IO} = 1.7 V R_L = 60 Ω, C_L = 100 pF, $C_{L(RXD)}$ = 15 pF See Figure 7-4		165	255	ns
$t_{PROP(LOOP2)}$	Total loop delay Driver input (TXD) to receiver output (RXD), dominant to recessive	STB = 0 V, V_{IO} = 2.8 V to 5.5 V R_L = 60 Ω, C_L = 100 pF, $C_{L(RXD)}$ = 15 pF See Figure 7-4		150	210	ns
$t_{PROP(LOOP2)}$	Total loop delay Driver input (TXD) to receiver output (RXD), dominant to recessive	STB = 0 V, V_{IO} = 1.7 V R_L = 60 Ω, C_L = 100 pF, $C_{L(RXD)}$ = 15 pF See Figure 7-4		180	255	ns
t_{MODE}	Mode change time, from normal to standby or from standby to normal	See Figure 7-5			20	µs
t_{WK_FILTER}	Filter time for a valid wake-up pattern	See Figure 8-5	0.5		1.8	µs
$t_{WK\_TIMEOUT}$	Bus wake-up timeout		0.8		6	ms
Driver Switching Characteristics						
t_{pHR}	Propagation delay time, high TXD to driver recessive (dominant to recessive)	STB = 0 V R_L = 60 Ω, C_L = 100 pF See Figure 7-2		80		ns
t_{pLD}	Propagation delay time, low TXD to driver dominant (recessive to dominant)			70		ns
$t_{sk(p)}$	Pulse skew (|tpHR - tpLD|)			14		ns
t_R	Differential output signal rise time			28		ns
t_F	Differential output signal fall time			50		ns
t_{TXD_DTO}	Dominant timeout	See Figure 7-6	1.2		4.0	ms
Receiver Switching Characteristics						
t_{pRH}	Propagation delay time, bus recessive input to high output (dominant to recessive)	STB = 0 V $C_{L(RXD)}$ = 15 pF See Figure 7-3		81		ns
t_{pDL}	Propagation delay time, bus dominant input to low output (recessive to dominant)			66		ns
t_R	RXD output signal rise time			10		ns
t_F	RXD output signal fall time			10		ns
FD Timing Characteristics						

6.9 Switching Characteristics (continued)

Over recommended operating conditions with T_A = -40℃ to 150℃ (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{BIT(BUS)}$	Bit time on CAN bus output pins $t_{BIT(TXD)}$ = 500 ns	STB = 0 V R_L = 60 Ω, C_L = 100 pF, $C_{L(RXD)}$ = 15 pF Δt_{REC} = $t_{BIT(RXD)}$ - $t_{BIT(BUS)}$ See Figure 7-4	450		525	ns
	Bit time on CAN bus output pins $t_{BIT(TXD)}$ = 200 ns		160		205	ns
	Bit time on CAN bus output pins $t_{BIT(TXD)}$ = 125 ns[1]		85		130	ns
$t_{BIT(RXD)}$	Bit time on RXD output pins $t_{BIT(TXD)}$ = 500 ns		410		540	ns
	Bit time on RXD output pins $t_{BIT(TXD)}$ = 200 ns		130		210	ns
	Bit time on RXD output pins $t_{BIT(TXD)}$ = 125 ns[1]		75		135	ns
Δt_{REC}	Receiver timing symmetry $t_{BIT(TXD)}$ = 500 ns		-50		20	ns
	Receiver timing symmetry $t_{BIT(TXD)}$ = 200 ns		-40		10	ns
	Receiver timing symmetry $t_{BIT(TXD)}$ = 125 ns[1]		-40		10	ns

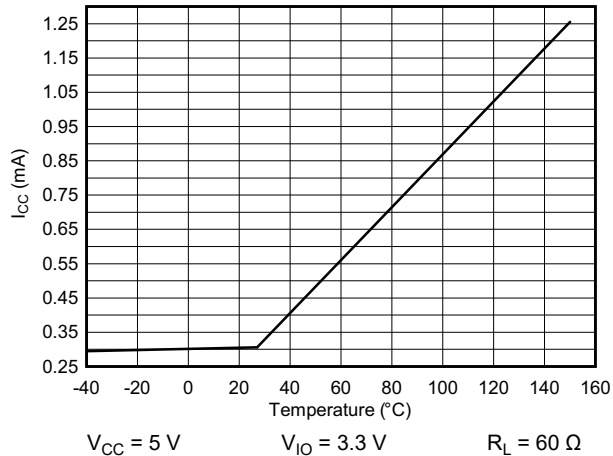(1)   Measured during characterization and not an ISO 11898-2:2016 parameter.
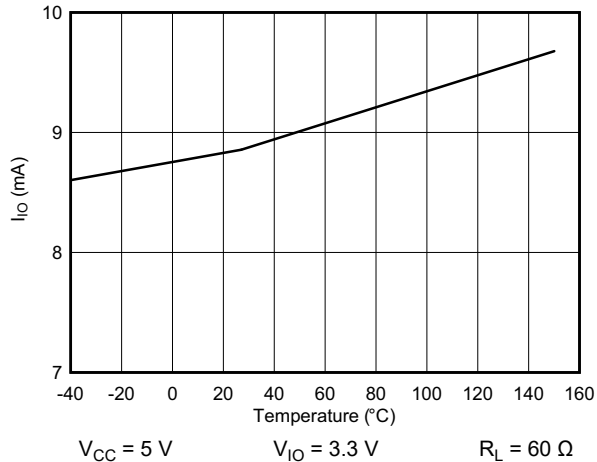
6.10 Typical Characteristics
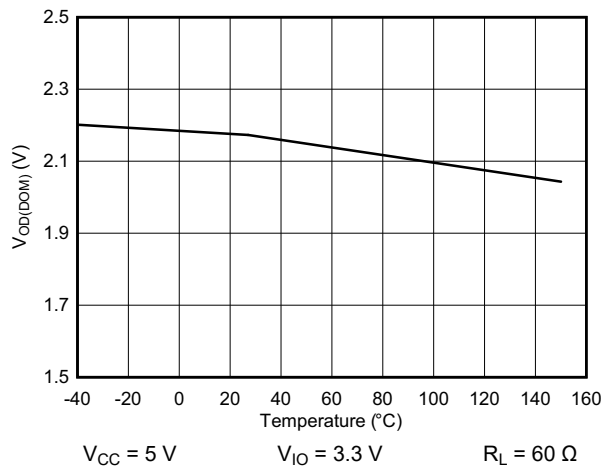
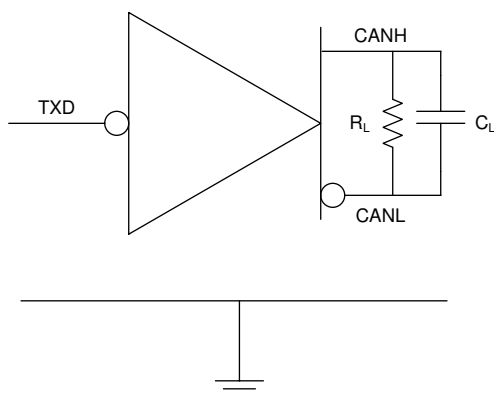**Figure 6-1. V$_{OD(DOM)}$ vs Temperature**

V_{CC} = 5 V V_{IO} = 3.3 V R_L = 60 Ω
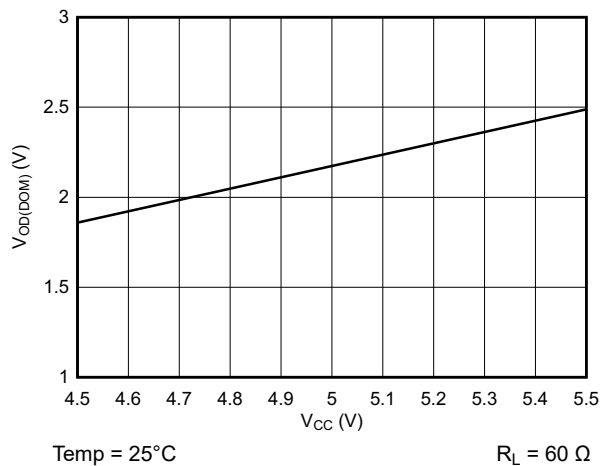
Figure 6-2. V$_{OD(DOM)}$ vs V$_{CC}$

Temp = 25°C R_L = 60 Ω

Figure 6-3. I$_{CC}$ Standby vs Temperature

V_{CC} = 5 V V_{IO} = 3.3 V R_L = 60 Ω

Figure 6-4. I$_{IO}$ Standby vs Temperature

V_{CC} = 5 V V_{IO} = 3.3 V R_L = 60 Ω

Product Folder Links: *TCAN1044AEV-Q1*
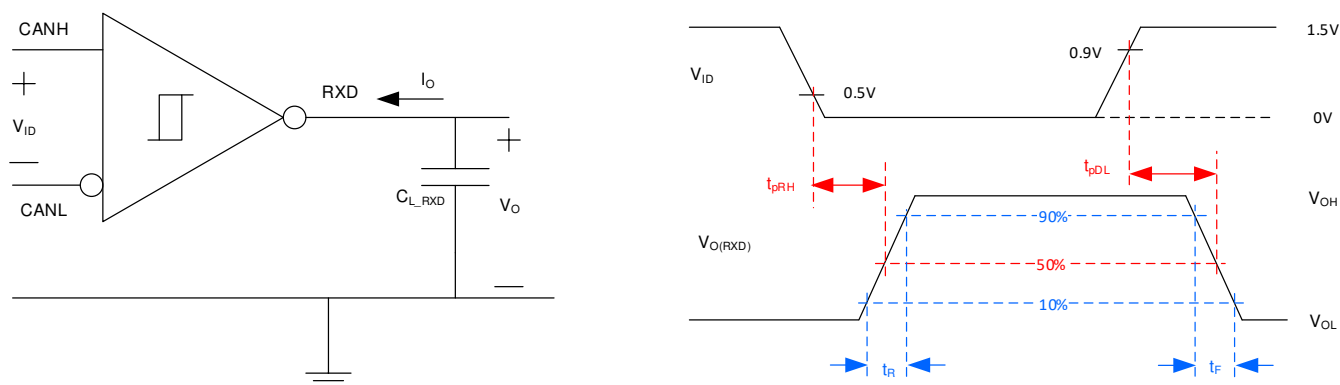
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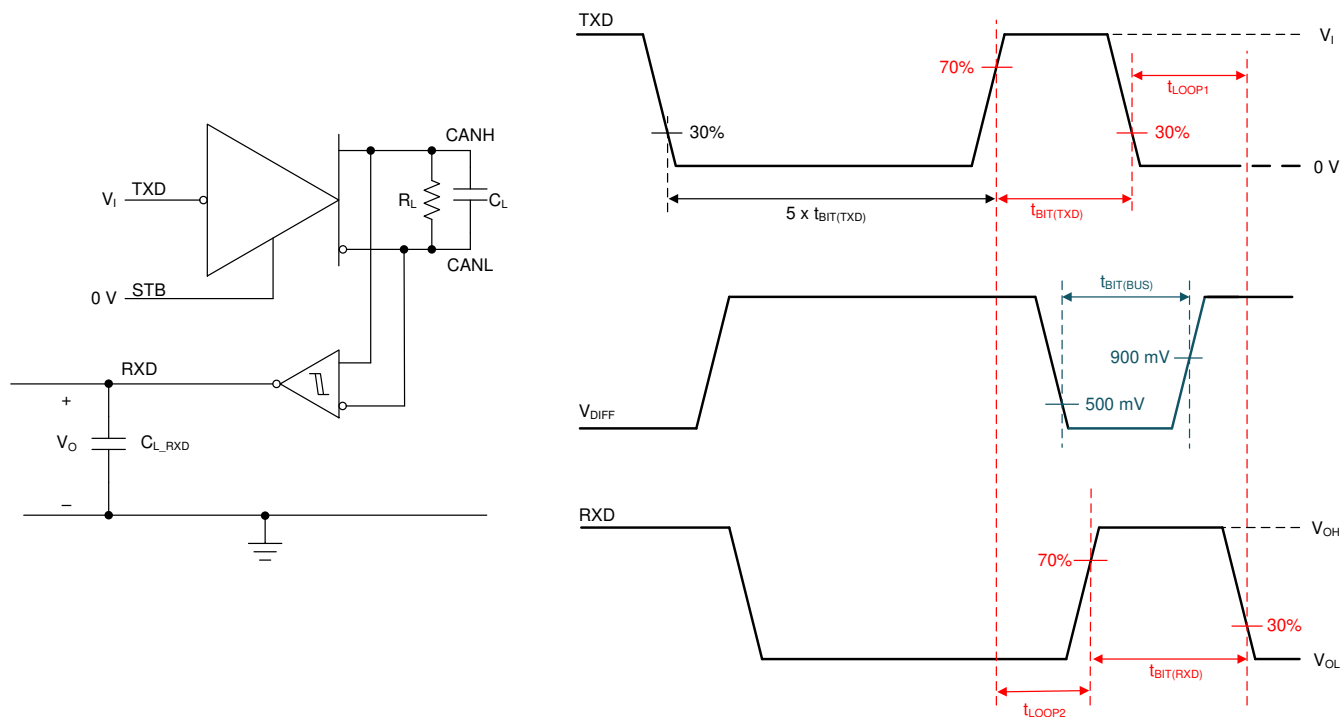

Figure 7-1. I_{CC} Test Circuit
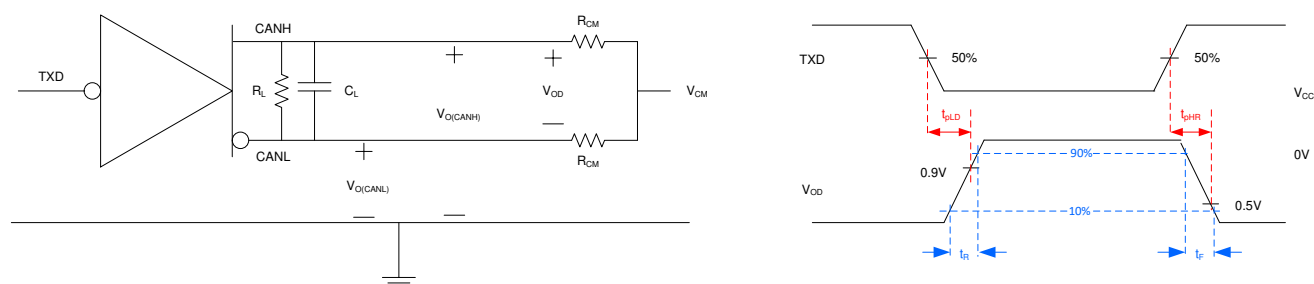
Figure 7-2. Driver Test Circuit and Measurement

Figure 7-3. Receiver Test Circuit and Measurement

Figure 7-4. Transmitter and Receiver Timing Test Circuit and Measurement
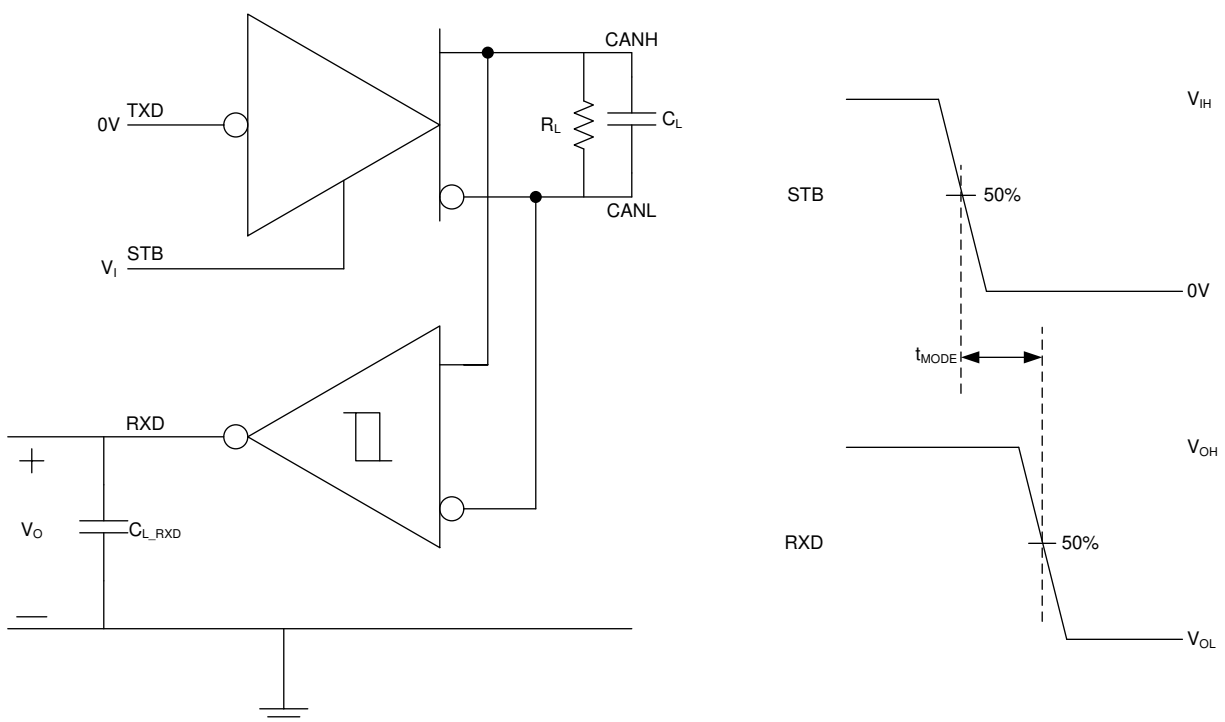
Figure 7-5. t_{MODE} Test Circuit and Measurement

Product Folder Links: *TCAN1044AEV-Q1*
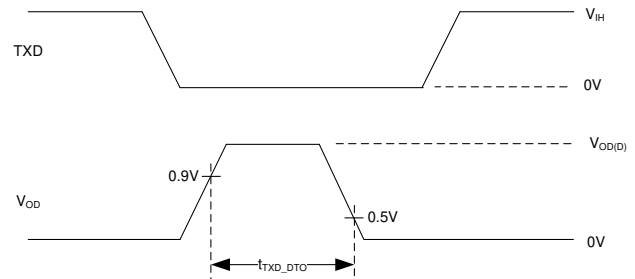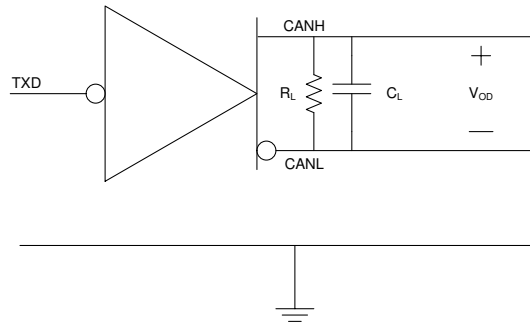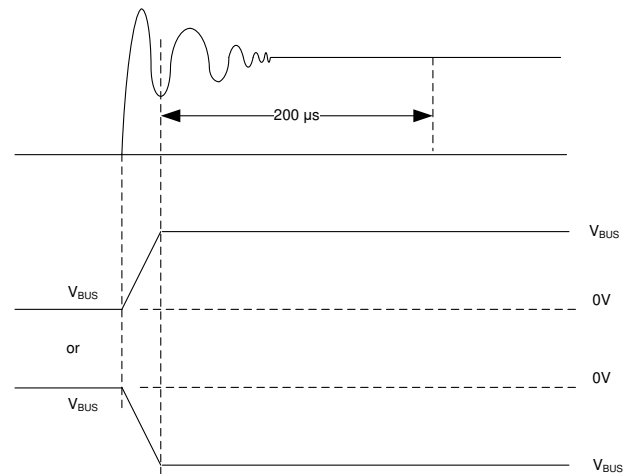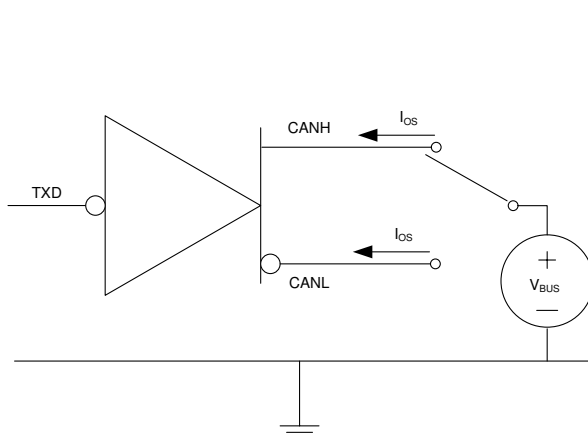
Figure 7-6. TXD Dominant Timeout Test Circuit and Measurement

Figure 7-7. Driver Short-Circuit Current Test and Measurement

Product Folder Links: *TCAN1044AEV-Q1*

8 Detailed Description

8.1 Overview

The TCAN1044AEV-Q1 meets or exceeds the specifications of the ISO 11898-2:2016 high-speed CAN (Controller Area Network) physical layer standard. The devices have been certified to the requirements of ISO 11898-2:2016 physical layer requirements according to the GIFT/ICT high speed CAN test specification. The transceivers provide a number of different protection features making it ideal for the stringent automotive system requirements while also supporting CAN FD data rates up to 8 Mbps.

The TCAN1044AEV-Q1 supports the following CAN and CAN FD standards:

- Physical layer:
  - ISO 11898-2:2016 High-speed medium access unit
  - ISO 11898-5:2007 High-speed medium access unit with low-power mode
  - SAE J2284-1: High-Speed CAN (HSC) for Vehicle Applications at 125 kbps
  - SAE J2284-2: High-Speed CAN (HSC) for Vehicle Applications at 250 kbps
  - SAE J2284-3: High-Speed CAN (HSC) for Vehicle Applications at 500 kbps
  - SAE J2284-4: High-Speed CAN (HSC) for Vehicle Applications at 500 kbps with CAN FD Data at 2 Mbps
  - SAE J2284-5: High-Speed CAN (HSC) for Vehicle Applications at 500 kbps with CAN FD Data at 5 Mbps
- EMC Requirements
  - IEC 62228-3 EMC evaluation of transceivers - CAN transceivers
  - VeLIO (Vehicle LAN Interoperability and Optimization) CAN and CAN-FD Transceiver Requirements
  - SAE J2962-2 Communication Transceivers Qualification Requirements – CAN

- Conformance test requirements:
  - ISO 16845-2 Road vehicles – Controller area network (CAN) conformance test plan Part 2: High-speed medium access unit conformance test plan

8.2 Functional Block Diagram
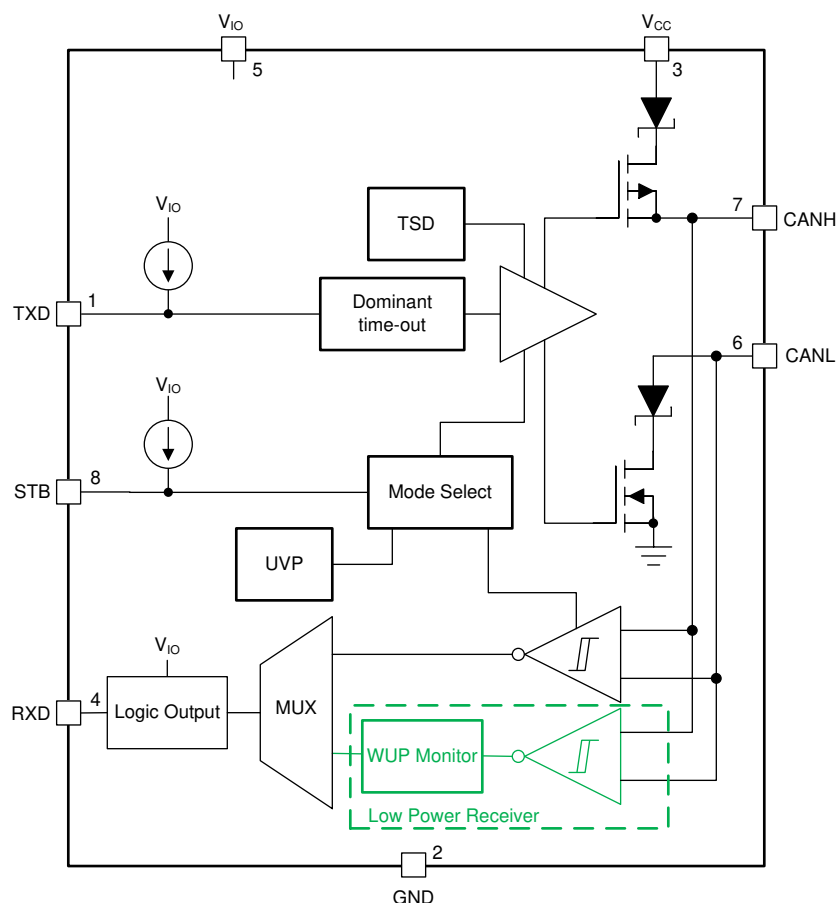
Figure 8-1. Block Diagram

8.3 Feature Description

8.3.1 Pin Description

8.3.1.1 TXD

The TXD input is a logic-level signal, referenced to V_{IO} from a CAN controller to the transceiver.

8.3.1.2 GND

GND is the ground pin of the transceiver. The pin must be connected to the PCB ground.

8.3.1.3 V_{CC}

V_{CC} provides the 5-V power supply to the CAN transceiver.

8.3.1.4 RXD

RXD is the logic-level signal, referenced to V_{IO}, from the TCAN1044AEV-Q1 to a CAN controller. This pin is only driven once V_{IO} is present.

8.3.1.5 V_{IO}

The V_{IO} pin provides the digital I/O voltage to match the CAN controller voltage thus avoiding the requirement for a level shifter. It supports voltages from 1.7 V to 5.5 V providing the widest range of controller support.

8.3.1.6 CANH and CANL

The CANH and CANL pins are the CAN high and CAN low differential bus pins. These pins are internally connected to the CAN transmitter, receiver and the low-power wake-up receiver.

Product Folder Links: *TCAN1044AEV-Q1*

8.3.1.7 STB (Standby)

The STB pin is an input pin used for mode control of the transceiver. The STB pin can be supplied from either the system processor or from a static system voltage source. If normal mode is the only intended mode of operation, the STB pin can be tied directly to GND.

8.3.2 CAN Bus States

The CAN bus has two logical states during operation: recessive and dominant. See Figure 8-2 and Figure 8-3.

A dominant bus state occurs when the bus is driven differentially and corresponds to a logic low on the TXD and RXD pins. A recessive bus state occurs when the bus is biased to $V_{CC}/2$ via the high-resistance internal input resistors (R_{IN}) of the receiver and corresponds to a logic high on the TXD and RXD pins.

A dominant state overwrites the recessive state during arbitration. Multiple CAN nodes may be transmitting a dominant bit at the same time during arbitration, and in this case the differential voltage of the bus is greater than the differential voltage of a single driver.

The TCAN1044AEV-Q1 transceiver implements a low-power standby (STB) mode which enables a third bus state where the bus pins are weakly biased to ground via the high resistance internal resistors of the receiver. See Figure 8-2 and Figure 8-3.
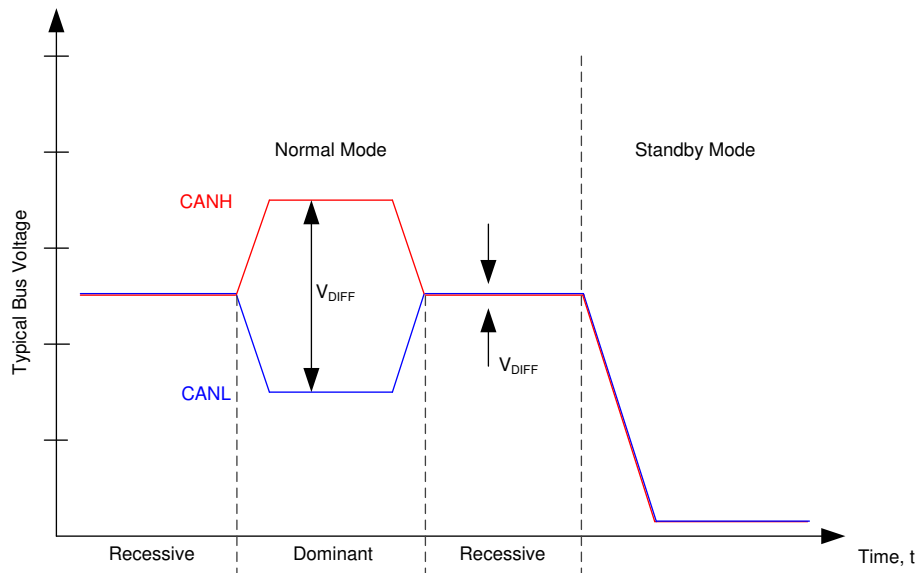
Figure 8-2. Bus States
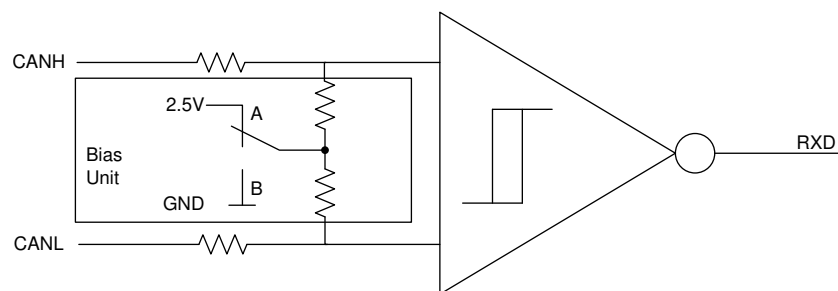
A.   A - Normal Mode B - Standby Mode

Figure 8-3. Simplified Recessive Common Mode Bias Unit and Receiver

Product Folder Links: *TCAN1044AEV-Q1*

8.3.3 TXD Dominant Timeout (DTO)

During normal mode, the only mode where the CAN driver is active, the TXD DTO circuit prevents the local node from blocking network communication in the event of a hardware or software failure where TXD is held dominant longer than the timeout period t_{TXD_DTO}. The TXD DTO circuit is triggered by a falling edge on TXD. If no rising edge is seen before the timeout period of the circuit, t_{TXD_DTO}, the CAN driver is disabled. This frees the bus for communication between other nodes on the network. The CAN driver is reactivated when a recessive signal is seen on the TXD pin, thus clearing the dominant time out. The receiver remains active and biased to $V_{CC}/2$ and the RXD output reflects the activity on the CAN bus during the TXD DTO fault.

The minimum dominant TXD time allowed by the TXD DTO circuit limits the minimum possible transmitted data rate of the device. The CAN protocol allows a maximum of eleven successive dominant bits (on TXD) for the worst case, where five successive dominant bits are followed immediately by an error frame. The minimum transmitted data rate may be calculated using Equation 1.

Minimum Data Rate = 11 bits / t_{TXD_DTO} = 11 bits / 1.2 ms = 9.2 kbps$\qquad$(1)
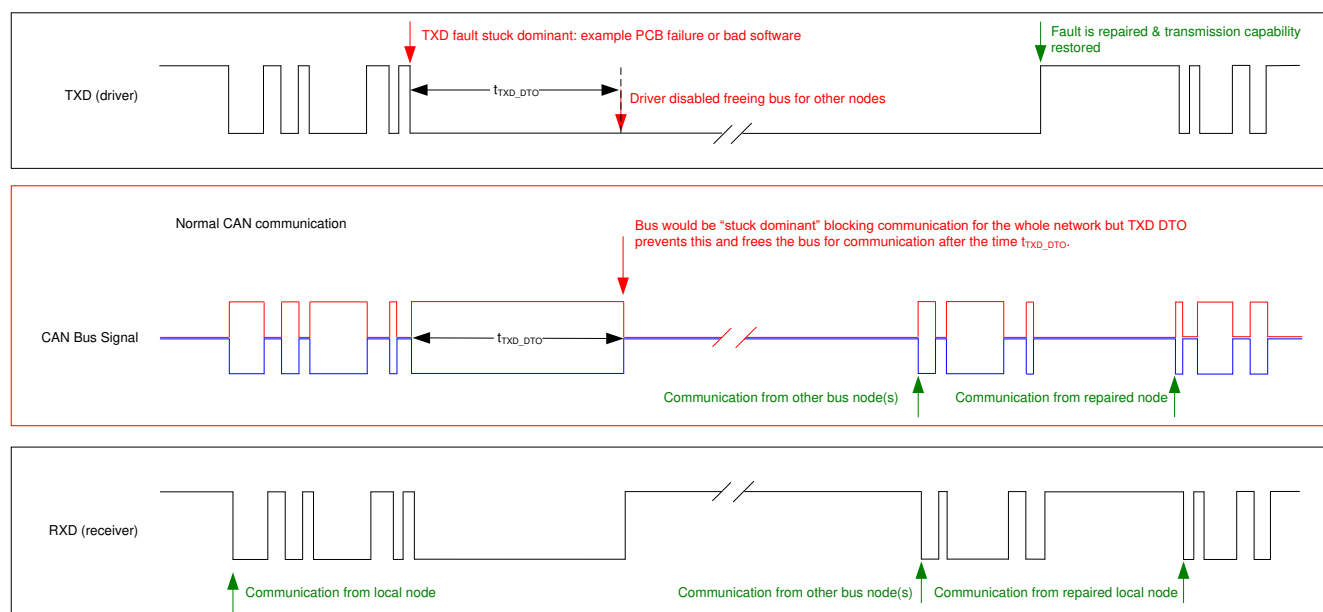
Figure 8-4. Example Timing Diagram for TXD Dominant Timeout

8.3.4 CAN Bus Short-Circuit Current Limiting

The TCAN1044AEV-Q1 has several protection features that limit the short-circuit current when a CAN bus line is shorted. These include CAN driver current limiting in the dominant and recessive states and TXD dominant state timeout which prevents permanently having the higher short-circuit current of a dominant state in case of a system fault. During CAN communication the bus switches between the dominant and recessive states, thus the short-circuit current may be viewed as either the current during each bus state or as a DC average current. When selecting termination resistors or a common-mode choke for the CAN design the average power rating, $I_{OS(AVG)}$, should be used. The percentage dominant is limited by the TXD DTO and the CAN protocol which has forced state changes and recessive bits due to bit stuffing, control fields, and interframe space. These ensure there is a minimum amount of recessive time on the bus even if the data field contains a high percentage of dominant bits.

The average short-circuit current of the bus depends on the ratio of recessive to dominant bits and their respective short-circuit currents. The average short-circuit current may be calculated using Equation 2.

$I_{OS(AVG)}$ = % Transmit x [(% REC_Bits x $I_{OS(SS)\_REC}$) + (% DOM_Bits x $I_{OS(SS)\_DOM}$)] + [% Receive x $I_{OS(SS)\_REC}$]$\quad$(2)

Where:

- $I_{OS(AVG)}$ is the average short-circuit current
- % Transmit is the percentage the node is transmitting CAN messages
- % Receive is the percentage the node is receiving CAN messages
- % REC_Bits is the percentage of recessive bits in the transmitted CAN messages
- % DOM_Bits is the percentage of dominant bits in the transmitted CAN messages
- $I_{OS(SS)\_REC}$ is the recessive steady state short-circuit current
- $I_{OS(SS)\_DOM}$ is the dominant steady state short-circuit current

This short-circuit current and the possible fault cases of the network should be taken into consideration when sizing the power supply used to generate the transceivers V_{CC} supply.

8.3.5 Thermal Shutdown (TSD)

If the junction temperature of the TCAN1044AEV-Q1 exceeds the thermal shutdown threshold, T_{TSD}, the device turns off the CAN driver circuitry and blocks the TXD to bus transmission path. The shutdown condition is cleared when the junction temperature of the device drops below T_{TSD}. The CAN bus pins are biased to $V_{CC}/2$ during a TSD fault and the receiver to RXD path remains operational. The TCAN1044AEV-Q1 TSD circuit includes hysteresis which prevents the CAN driver output from oscillating during a TSD fault.

8.3.6 Undervoltage Lockout

The supply pins, V_{CC} and V_{IO}, have undervoltage detection that places the device into a protected state. This protects the bus during an undervoltage event on either supply pin.

Table 8-1. Undervoltage Lockout - TCAN1044AEV-Q1

V_{CC}	V_{IO}	DEVICE STATE	BUS	RXD PIN
> UV$_{VCC}$	> UV$_{VIO}$	Normal	Per TXD	Mirrors bus
< UV$_{VCC}$	> UV$_{VIO}$	STB = High: Standby Mode	Weak biased to GND	V_{IO}: Remote wake request See Remote Wake Request via Wake-Up Pattern (WUP) in Standby Mode
		STB =Low: Protected Mode	High impedance	Recessive
> UV$_{VCC}$	< UV$_{VIO}$	Protected	High impedance	High impedance
< UV$_{VCC}$	< UV$_{VIO}$	Protected	High impedance	High impedance

Once the undervoltage condition is cleared and t_{MODE} has expired the TCAN1044AEV-Q1 will transition to normal mode and the host controller can send and receive CAN traffic again

8.3.7 Unpowered Device

The TCAN1044AEV-Q1 is designed to be an ideal passive or no load to the CAN bus if the device is unpowered. The bus pins were designed to have low leakage currents when the device is unpowered, so they do not load the bus. This is critical if some nodes of the network are unpowered while the rest of the of network remains operational.

The logic pins also have low leakage currents when the device is unpowered, so they do not load other circuits which may remain powered.

8.3.8 Floating pins

The TCAN1044AEV-Q1 has internal pull-ups on critical pins which place the device into known states if the pin floats. This internal bias should not be relied upon by design though, especially in noisy environments, but instead should be considered a failsafe protection feature.

When a CAN controller supporting open-drain outputs is used an adequate external pull-up resistor must be chosen. This ensures that the TXD output of the CAN controller maintains acceptable bit time to the input of the CAN transceiver. See Table 8-2 for details on pin bias conditions.

Table 8-2. Pin Bias

Pin	Pull-up or Pull-down	Comment
TXD	Pull-up	Weakly biases TXD towards recessive to prevent bus blockage or TXD DTO triggering
STB	Pull-up	Weakly biases STB towards low-power standby mode to prevent excessive system power

8.4 Device Functional Modes

8.4.1 Operating Modes

The TCAN1044AEV-Q1 has two main operating modes; normal mode and standby mode. Operating mode selection is made by applying a high or low level to the STB pin.

Table 8-3. Operating Modes

STB	Device Mode	Driver	Receiver	RXD Pin
High	Low current standby mode with bus wake-up	Disabled	Low-power receiver and bus monitor enable	High (recessive) until valid WUP is received. See Remote Wake Request via Wake-Up Pattern (WUP) in Standby Mode
Low	Normal Mode	Enabled	Enabled	Mirrors bus state

8.4.2 Normal Mode

This is the normal operating mode of the TCAN1044AEV-Q1. The CAN driver and receiver are fully operational and CAN communication is bi-directional.

The driver is translating a digital input on the TXD input to a differential output on the CANH and CANL bus pins.

The receiver is translating the differential signal from CANH and CANL to a digital output on the RXD output.

8.4.3 Standby Mode

This is the low-power mode of the TCAN1044AEV-Q1. The CAN driver and main receiver are switched off and bi-directional CAN communication is not possible. The low-power receiver and bus monitor circuits are enabled to allow for RXD wake-up requests via the CAN bus. A wake-up request is output to RXD as shown in Figure 8-5. The local CAN protocol controller should monitor RXD for transitions (high-to-low) and reactivate the device to normal mode by pulling the STB pin low. The CAN bus pins are weakly pulled to GND in this mode; see Figure 8-2 and Figure 8-3.

In standby mode, only the V_{IO} supply is required; therefore, the V_{CC} may be switched off for additional system level current savings.

8.4.3.1 Remote Wake Request via Wake-Up Pattern (WUP) in Standby Mode

The TCAN1044AEV-Q1 supports a remote wake-up request that is used to indicate to the host controller that the bus is active and the node should return to normal operation.

The device uses the multiple filtered dominant wake-up pattern (WUP) from the ISO 11898-2:2016 standard to qualify bus activity. Once a valid WUP has been received, the wake request is indicated to the controller by a falling edge and low period corresponding to a filtered dominant on the RXD output of the TCAN1044AEV-Q1.

The WUP consists of a filtered dominant pulse, followed by a filtered recessive pulse, and finally by a second filtered dominant pulse. The first filtered dominant initiates the WUP, and the bus monitor then waits on a filtered recessive; other bus traffic does not reset the bus monitor. Once a filtered recessive is received the bus monitor is waiting for a filtered dominant and again, other bus traffic does not reset the bus monitor. Immediately upon reception of the second filtered dominant the bus monitor recognizes the WUP and drives the RXD output low every time an additional filtered dominant signal is received from the bus.

For a dominant or recessive to be considered filtered, the bus must be in that state for more than the t_{WK_FILTER} time. Due to variability in t_{WK_FILTER} the following scenarios are applicable. Bus state times less than

$t_{WK\_FILTER(MIN)}$ are never detected as part of a WUP and thus no wake request is generated. Bus state times between $t_{WK\_FILTER(MIN)}$ and $t_{WK\_FILTER(MAX)}$ may be detected as part of a WUP and a wake-up request may be generated. Bus state times greater than $t_{WK\_FILTER(MAX)}$ are always detected as part of a WUP, and thus a wake request is always generated. See Figure 8-5 for the timing diagram of the wake-up pattern.

The pattern and t_{WK_FILTER} time used for the WUP prevents noise and bus stuck dominant faults from causing false wake-up requests while allowing any valid message to initiate a wake-up request.

The ISO 11898-2:2016 standard has defined times for a short and long wake-up filter time. The t_{WK_FILTER} timing for the device has been picked to be within the minimum and maximum values of both filter ranges. This timing has been chosen such that a single bit time at 500 kbps, or two back-to-back bit times at 1 Mbps triggers the filter in either bus state. Any CAN frame at 500 kbps or less would contain a valid WUP.

For an additional layer of robustness and to prevent false wake-ups, the device implements a wake-up timeout feature. For a remote wake-up event to successfully occur, the entire WUP must be received within the timeout value $t \leq t_{WK\_TIMEOUT}$. If not, the internal logic is reset and the transceiver remains in its current state without waking up. The full pattern must then be transmitted again, conforming to the constraints mentioned in this section. See Figure 8-5 for the timing diagram of the wake-up pattern with wake timeout feature.
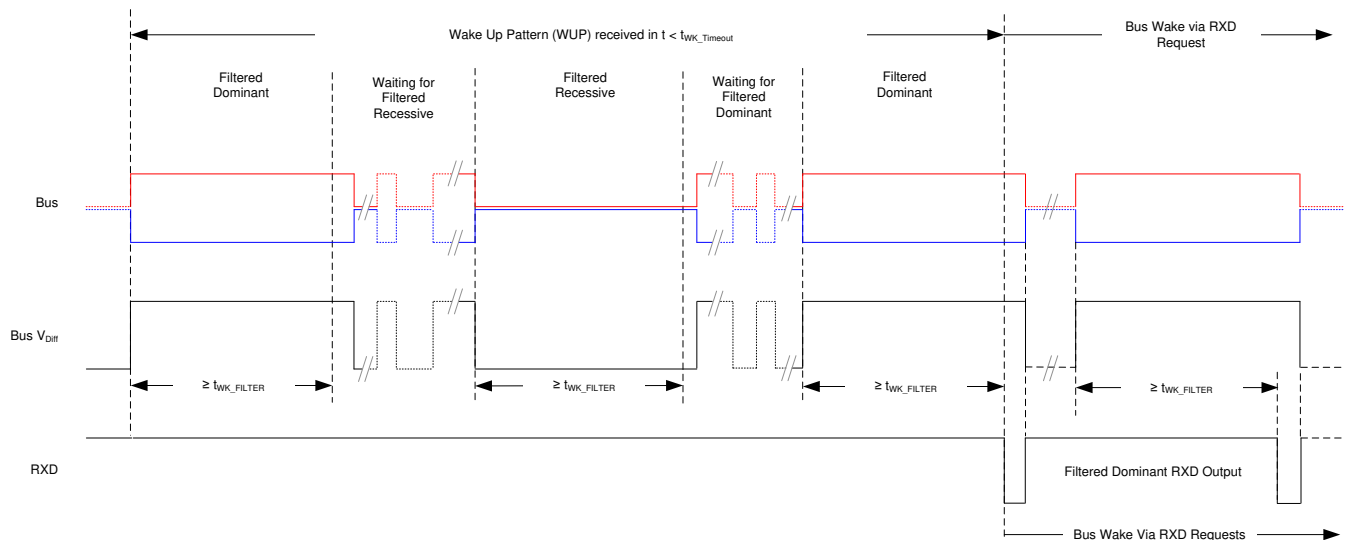
Figure 8-5. Wake-Up Pattern (WUP) with $t_{WK\_TIMEOUT}$

8.4.4 Driver and Receiver Function

The TCAN1044AEV-Q1 logic I/Os support CMOS levels with respect to V_{IO} for compatibility with MCUs that support 1.8-V, 2.5-V, 3.3-V, or 5-V systems.

Table 8-4. Driver Function Table

Device Mode	TXD Input[1]	Bus Outputs		Driven Bus State[2]
		CANH	CANL	
Normal	Low	High	Low	Dominant
	High or open	High impedance	High impedance	Biased recessive
Standby	X	High impedance	High impedance	Biased to ground

(1) X = irrelevant
(2) For bus state and bias see Figure 8-2 and Figure 8-3

Table 8-5. Receiver Function Table Normal and Standby Mode

Device Mode	CAN Differential Inputs $V_{ID} = V_{CANH} - V_{CANL}$	Bus State	RXD Pin
Normal	$V_{ID} ≥ 0.9$ V	Dominant	Low
	0.5 V $< V_{ID} < 0.9$ V	Undefined	Undefined
	$V_{ID} ≤ 0.5$ V	Recessive	High
Standby	$V_{ID} ≥ 1.15$ V	Dominant	High Low if a remote wake event occurred See Figure 8-5
	0.4 V $< V_{ID} < 1.15$ V	Undefined	
	$V_{ID} ≤ 0.4$ V	Recessive	
Any	Open ($V_{ID} ≈ 0$ V)	Open	High

Product Folder Links: *TCAN1044AEV-Q1*

9 Application Information Disclaimer

> **Note**
>
> Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

9.2 Typical Application

The TCAN1044AEV-Q1 transceiver can be used in applications with a host controller or FPGA that includes the link layer portion of the CAN protocol. Figure 9-1 shows a typical configuration for 5-V controller applications. The bus termination is shown for illustrative purposes.
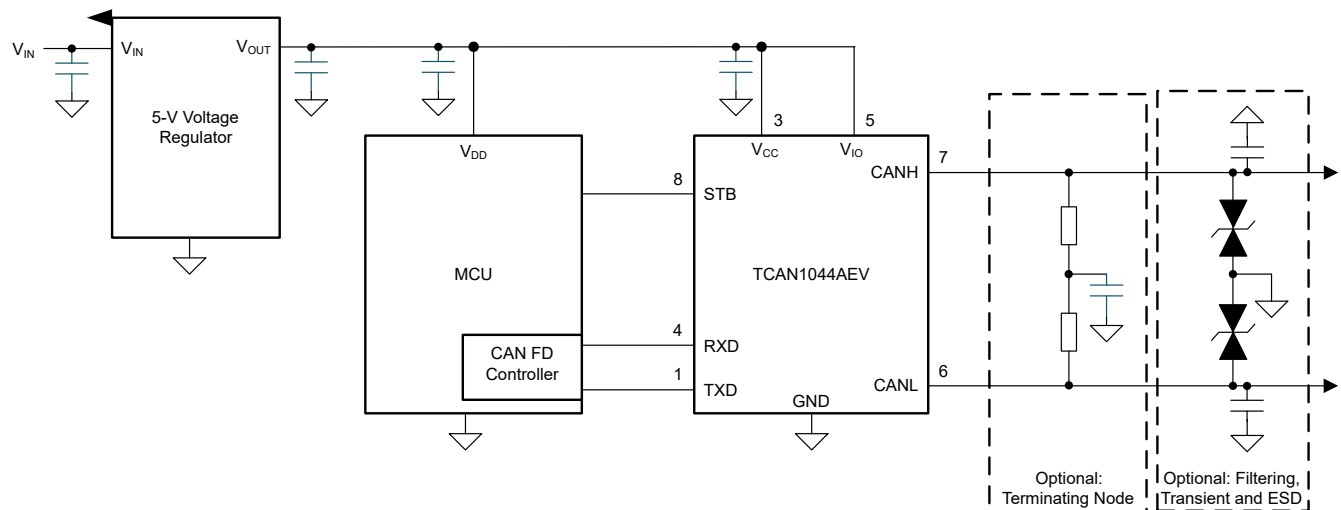

Figure 9-1. Transceiver Application Using 5-V IO Connections

9.2.1 Design Requirements

9.2.1.1 CAN Termination

Termination may be a single 120-Ω resistor at each end of the bus, either on the cable or in a terminating node. If filtering and stabilization of the common-mode voltage of the bus is desired then split termination may be used, see Figure 9-2. Split termination improves the electromagnetic emissions behavior of the network by filtering higher-frequency common-mode noise that may be present on the differential signal lines.

Product Folder Links: *TCAN1044AEV-Q1*

Standard Termination
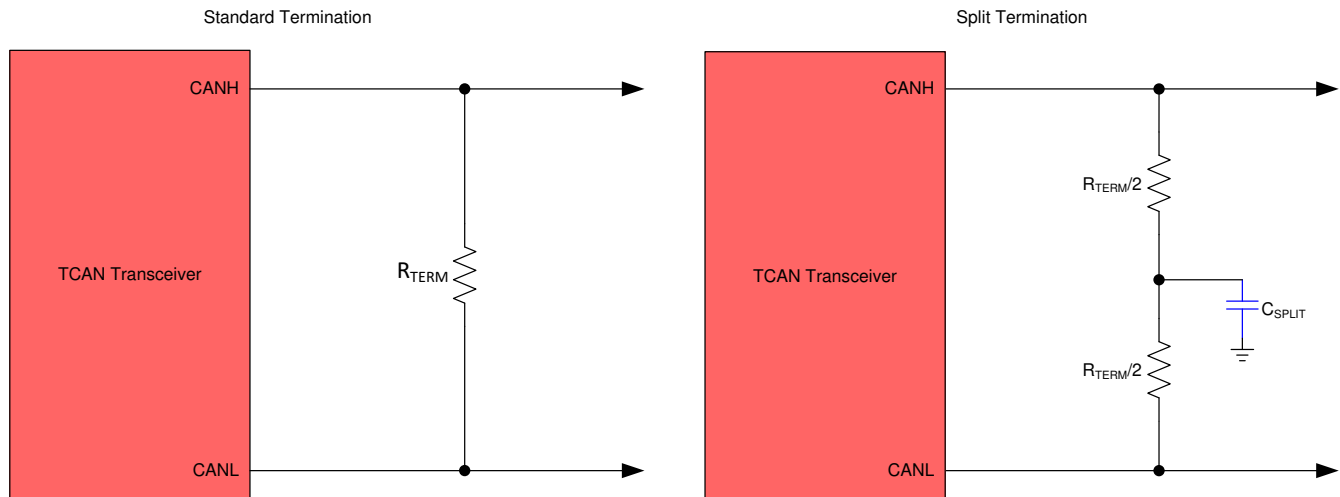
Split Termination

Figure 9-2. CAN Bus Termination Concepts

9.2.2 Detailed Design Procedures

9.2.2.1 Bus Loading, Length and Number of Nodes

A typical CAN application may have a maximum bus length of 40 meters and maximum stub length of 0.3 m. However, with careful design, users can have longer cables, longer stub lengths, and many more nodes to a bus. A high number of nodes requires a transceiver with high input impedance such as the TCAN1044AEV-Q1.

Many CAN organizations and standards have scaled the use of CAN for applications outside the original ISO 11898-2 standard. They made system level trade off decisions for data rate, cable length, and parasitic loading of the bus. Examples of these CAN systems level specifications are ARINC 825, CANopen, DeviceNet, SAE J2284, SAE J1939, and NMEA 2000.

A CAN network system design is a series of tradeoffs. In the ISO 11898-2:2016 specification the driver differential output is specified with a bus load that can range from 50 Ω to 65 Ω where the differential output must be greater than 1.5 V. The TCAN1044AEV-Q1 is specified to meet the 1.5-V requirement down to 50 Ω and is specified to meet 1.4-V differential output at 45-Ω bus load. The differential input resistance of the TCAN1044AEV-Q1 is a minimum of 40 kΩ. If 100 TCAN1044AEV-Q1 transceivers are in parallel on a bus, this is equivalent to a 400-Ω differential load in parallel with the nominal 60-Ω bus termination which gives a total bus load of approximately 52 Ω. Therefore, the TCAN1044AEV-Q1 theoretically supports over 100 transceivers on a single bus segment. However, for a CAN network design margin must be given for signal loss across the system and cabling, parasitic loadings, timing, network imbalances, ground offsets, and signal integrity thus a practical maximum number of nodes is often lower. Bus length may also be extended beyond 40 meters by careful system design and data rate tradeoffs. For example, CANopen network design guidelines allow the network to be up to 1 km with changes in the termination resistance, cabling, less than 64 nodes and significantly lowered data rate.

This flexibility in CAN network design is one of the key strengths of the various extensions and additional standards that have been built on the original ISO 11898-2 CAN standard. However, when using this flexibility the CAN network system designer must take the responsibility of good network design to ensure robust network operation.

Please refer to the application report SLLA270: Controller Area Network Physical layer requirements. This document discusses in detail all system design physical layer parameters.
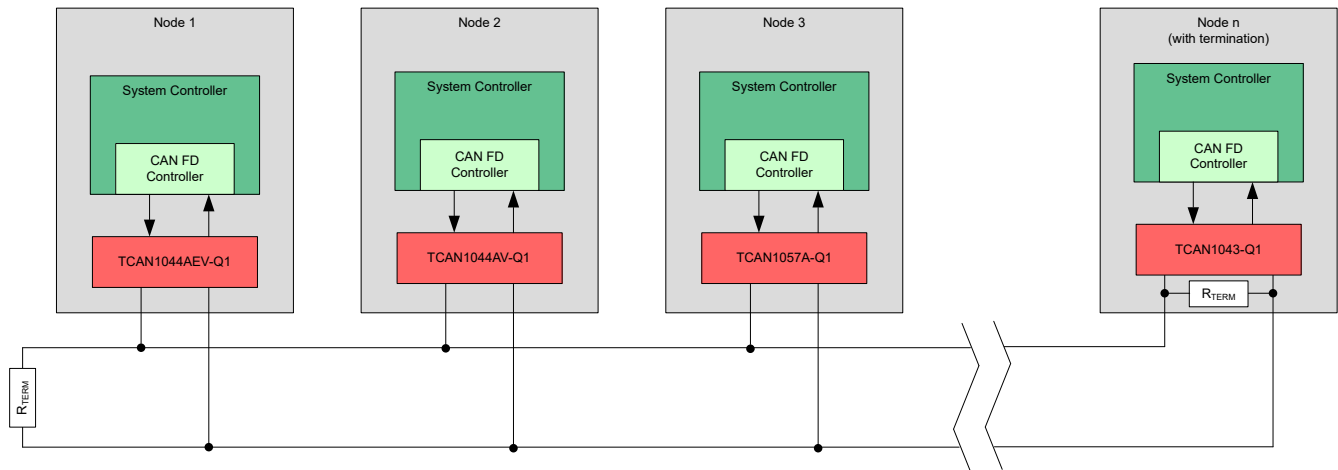
Figure 9-3. Typical CAN Bus

9.3 System Examples

The TCAN1044AEV-Q1 CAN transceiver is typically used in applications with a host controller or FPGA that includes the link layer portion of the CAN protocol. A 1.8-V, 2.5-V, or 3.3-V application is shown in Figure 9-4. The bus termination is shown for illustrative purposes.
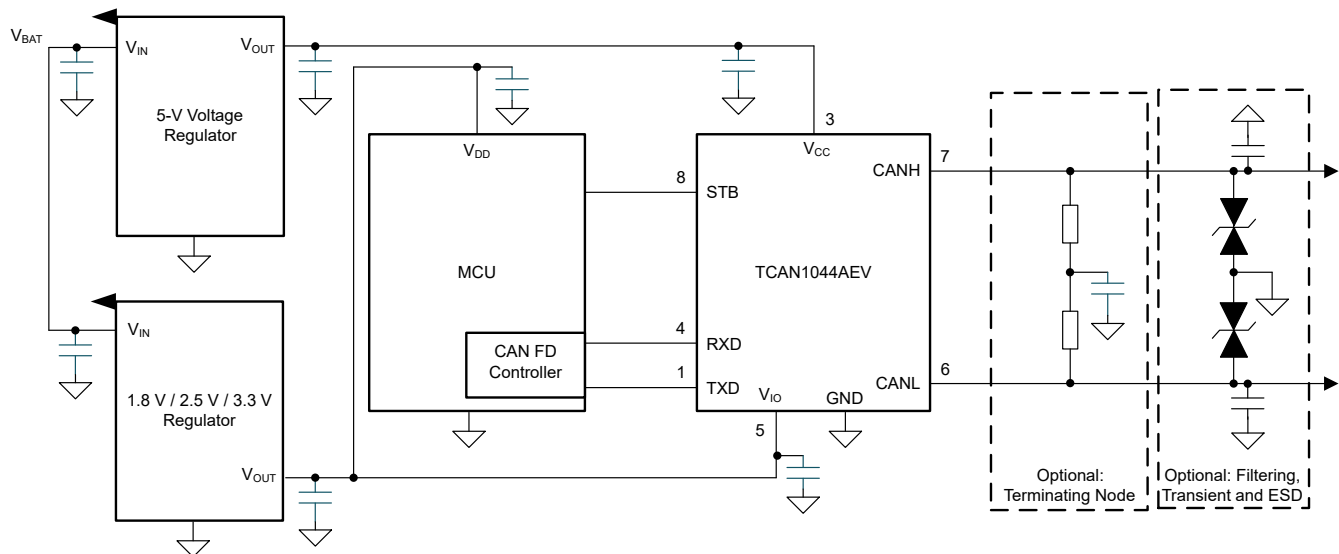

Figure 9-4. Typical Transceiver Application Using 1.8-V, 2.5-V, 3.3-V IO Connections

10 Power Supply Recommendations

The TCAN1044AEV-Q1 transceiver is designed to operate with a main V_{CC} input voltage supply range between 4.5 V and 5.5 V.

The device implements an I/O level shifting supply input, V_{IO}, designed for a range between 1.8 V and 5.5 V.

Both the V_{CC} and V_{IO} inputs must be well regulated. In addition to the power supply filtering a decoupling capacitance, typically 100 nF, should be placed near the CAN transceiver's main V_{CC} and V_{IO} supply pins.

11 Layout

Robust and reliable CAN node design may require special layout techniques depending on the application and design requirements. Since transient disturbances have high frequency content and a wide bandwidth, high-frequency layout techniques should be applied during PCB design.

11.1 Layout Guidelines

- Place the protection and filtering circuitry close to the bus connector, J1, to prevent transients, ESD, and noise from propagating onto the board. This layout example shows an optional transient voltage suppression (TVS) diode, D1, which may be implemented if the system-level requirements exceed the specified rating of the transceiver. This example also shows optional bus filter capacitors C4 and C5.
- Design the bus protection components in the direction of the signal path. Do not force the transient current to divert from the signal path to reach the protection device.
- Decoupling capacitors should be placed as close as possible to the supply pins V_{CC} and V_{IO} of transceiver.
- Use at least two vias for supply and ground connections of bypass capacitors and protection devices to minimize trace and via inductance.

Note

High-frequency current follows the path of least impedance and not the path of least resistance.

- This layout example shows how split termination could be implemented on the CAN node. The termination is split into two resistors, R2 and R3, with the center or split tap of the termination connected to ground via capacitor C3. Split termination provides common mode filtering for the bus. See Section 9.2.1.1, Section 8.3.4, and Equation 2 for information on termination concepts and power ratings needed for the termination resistor(s).

11.2 Layout Example
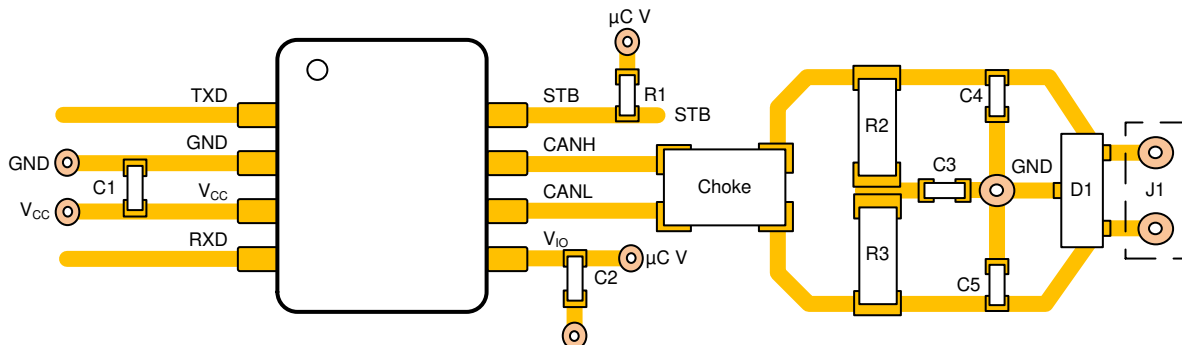
Figure 11-1. Layout Example

Product Folder Links: *TCAN1044AEV-Q1*

12 Device and Documentation Support

12.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.2 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

12.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.
All trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.5 Glossary

TI Glossary   This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TCAN1044AEVDDFRQ1	ACTIVE	SOT-23-THIN	DDF	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 150	2HJF	Samples
TCAN1044AEVDRQ1	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 150	44AEV	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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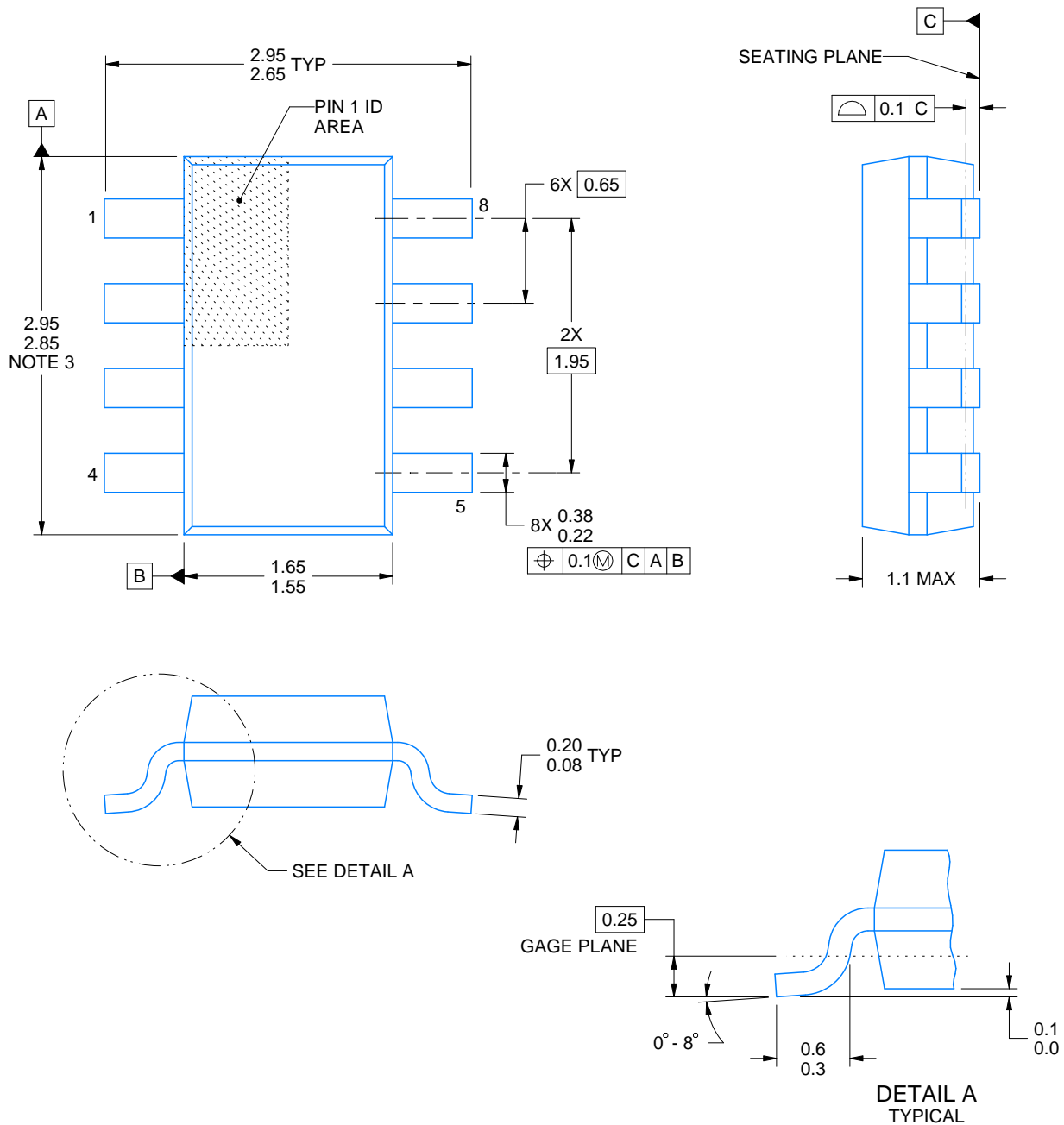
TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TCAN1044AEVDDFRQ1	SOT-23-THIN	DDF	8	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TCAN1044AEVDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TCAN1044AEVDDFRQ1	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
TCAN1044AEVDRQ1	SOIC	D	8	2500	356.0	356.0	35.0

2.95
2.65 TYP

A

PIN 1 ID
AREA

1

2.95
2.85
NOTE 3

4

B

1.65
1.55

8

6X 0.65

2X
1.95

5

8X 0.38
0.22

$\oplus$ 0.1Ⓜ C A B

C

SEATING PLANE

0.1 C

1.1 MAX

0.20 TYP
0.08

SEE DETAIL A

0.25
GAGE PLANE

0° - 8°

0.6
0.3

0.1
0.0

DETAIL A
TYPICAL

4222047/C   10/2022

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.

TEXAS
INSTRUMENTS
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8X (1.05)

SYMM

1

8

8X (0.45)

SYMM

6X (0.65)

4

5

(R0.05)
TYP

(2.6)
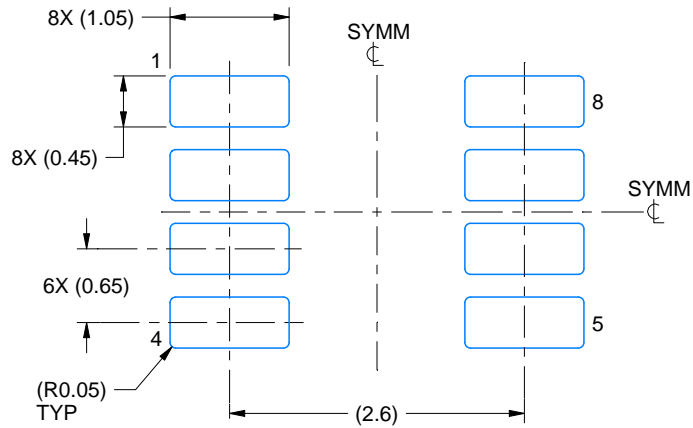
LAND PATTERN EXAMPLE
SCALE:15X

SOLDER MASK
OPENING

METAL

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING
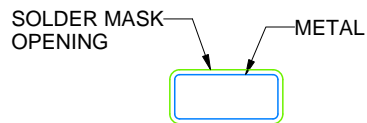
NON SOLDER MASK
DEFINED
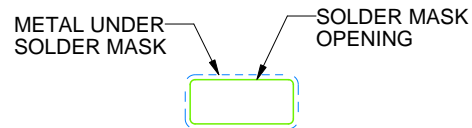
SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4222047/C   10/2022

NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

8X (1.05)

SYMM

(R0.05) TYP

1

8

8X (0.45)

SYMM

6X (0.65)

4

5

(2.6)

SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4222047/C   10/2022

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
7. Board assembly site may have different recommendations for stencil design.

.228-.244   TYP
[5.80-6.19]

A

PIN 1 ID AREA

1

8

6X .050
[1.27]

2X

.150
[3.81]

.189-.197
[4.81-5.00]
NOTE 3

4

5

8X .012-.020
[0.31-0.51]

B

.150-.157
[3.81-3.98]
NOTE 4

⊕ .010 [0.25]Ⓜ C A B

C

SEATING PLANE

◠ .004 [0.1] C

4X (0°-15°)

.069 MAX
[1.75]

SEE DETAIL A

4X (0°-15°)

.005-.010   TYP
[0.13-0.25]

.010
[0.25]

0°- 8°

.016-.050
[0.41-1.27]

(.041)
[1.04]

.004-.010
[0.11-0.25]

DETAIL A
TYPICAL

4214825/C   02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches.
   Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
   exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

8X (.061)
[1.55]

SYMM
$\mathbb{C}$

SEE
DETAILS

1

8

8X (.024)
[0.6]

SYMM
$\mathbb{C}$

(R.002) TYP
[0.05]

4

5

6X (.050)
[1.27]

(.213)
[5.4]

LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X

METAL

SOLDER MASK
OPENING

SOLDER MASK
OPENING

METAL UNDER
SOLDER MASK

EXPOSED
METAL

EXPOSED
METAL

.0028 MAX
[0.07]
ALL AROUND

.0028 MIN
[0.07]
ALL AROUND

NON SOLDER MASK
DEFINED

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4214825/C   02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

8X (.061)
[1.55]

SYMM

1

8X (.024)
[0.6]

SYMM

8

(R.002) TYP
[0.05]

4

5

6X (.050)
[1.27]

(.213)
[5.4]

SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C   02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate
   design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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